NSN 5961-01-415-4326

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View Online at https://aerobasegroup.com/nsn/5961-01-415-4326 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205af **Mounting Method: Terminal Features Provided:** Radiation hardened **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 100.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 8.00 amperes drain current **Power Rating Per Characteristic:** 25.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 34371-frl130d manufacturers specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli